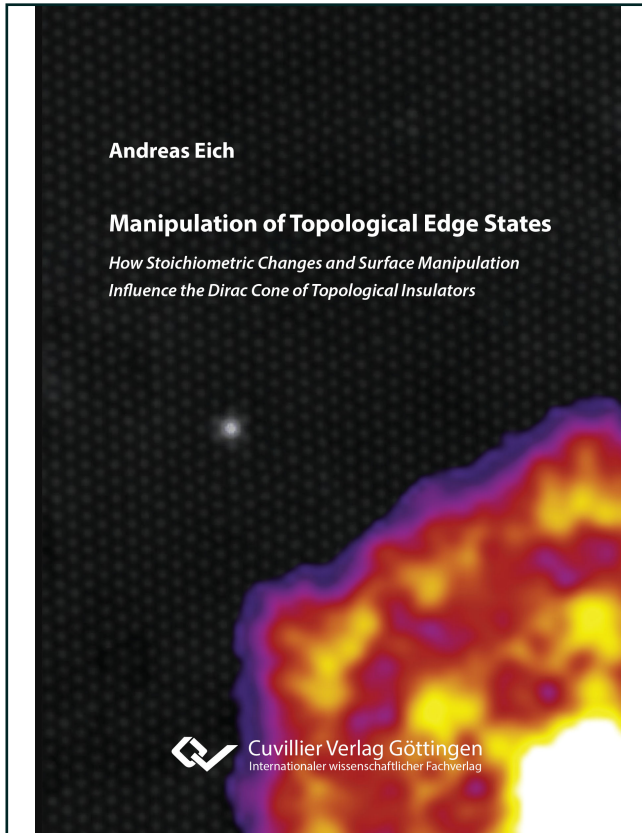




Andreas Eich (Autor)

Manipulation of Topological Edge States

How Stoichiometric Changes and Surface Manipulation
Influence the Dirac Cone of Topological Insulators



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